Low-Voltage CMOS Octal Transceiver

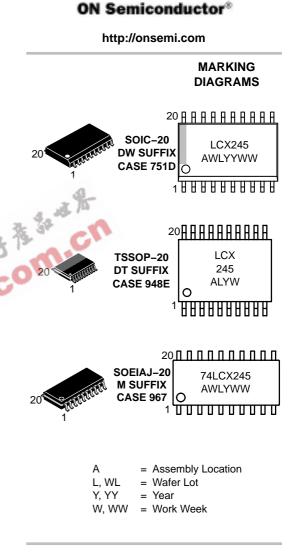
With 5 V–Tolerant Inputs and Outputs (3–State, Inverting)

The MC74LCX245 is a high performance, non-inverting octal transceiver operating from a 2.3 to 3.6 V supply. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A V_I specification of 5.5 V allows MC74LCX245 inputs to be safely driven from 5 V devices. The MC74LCX245 is suitable for memory address driving and all TTL level bus oriented transceiver applications.

Current drive capability is 24 mA at both A and B ports. The Transmit/Receive (T/\overline{R}) input determines the direction of data flow through the bi-directional transceiver. Transmit (active-HIGH) enables data from A ports to B ports; Receive (active-LOW) enables data from B to A ports. The Output Enable input, when HIGH, disables both A and B ports by placing them in a HIGH Z condition.

Features

- Designed for 2.3 to 3.6 V V_{CC} Operation
- 5 V Tolerant Interface Capability With 5 V TTL Logic
- Supports Live Insertion and Withdrawal
- I_{OFF} Specification Guarantees High Impedance When $V_{CC} = 0$ V
- LVTTL Compatible
- LVCMOS Compatible
- 24 mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current in All Three Logic States (10 µA) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500 mA
- ESD Performance: Human Body Model >2000 V Machine Model >200 V
- Pb–Free Packages are Available*



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

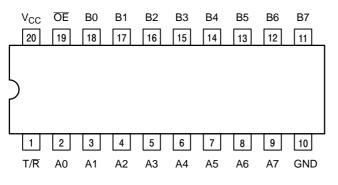


Figure 1. Pinout (Top View)



PINS	FUNCTION	
ŌE	Output Enable Input	
T/R	Transmit/Receive Input	
A0-A7	Side A 3–State Inputs or 3–State Outputs	
B0-B7	Side B 3–State Inputs or 3–StateOutputs	

TRUTH TABLE

INPUTS		OPERATING MODE
ŌĒ	T/R	Non-Inverting
L	L	B Data to A Bus
L	н	A Data to B Bus
н	х	Z

H = High Voltage Level L = Low Voltage Level

Z = High Impedance State

X = High or Low Voltage Level and Transitions are Acceptable For I_{CC} reasons, Do Not Float Inputs

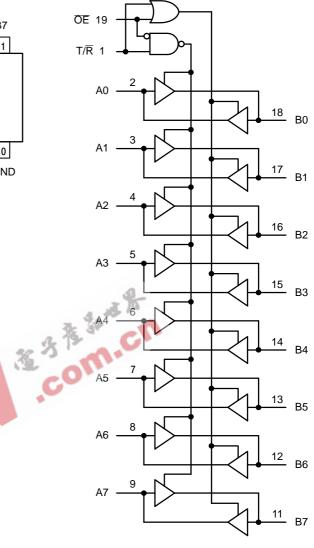


Figure 2. Logic Diagram

MAXIMUM RATINGS

Symbol	Parameter	Value	Condition	Unit
V_{CC}	DC Supply Voltage	-0.5 to +7.0		V
VI	DC Input Voltage	$-0.5 \le V_1 \le +7.0$		V
Vo	DC Output Voltage	$-0.5 \le V_{O} \le +7.0$	Output in 3-State	V
		$-0.5 \le V_O \le V_{CC} + 0.5$	Output in HIGH or LOW State (Note 1)	V
I _{IK}	DC Input Diode Current	-50	V _I < GND	mA
I _{OK}	DC Output Diode Current	-50	V _O < GND	mA
		+50	V _O > V _{CC}	mA
lo	DC Output Source/Sink Current	±50		mA
I _{CC}	DC Supply Current Per Supply Pin	±100		mA
I _{GND}	DC Ground Current Per Ground Pin	±100		mA
T _{STG}	Storage Temperature Range	-65 to +150		°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected. 1. I_O absolute maximum rating must be observed.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	3.13	Min	Тур	Мах	Unit
V _{CC}	Supply Voltage	Operating Data Retention Only	2.0 1.5	2.5, 3.3 2.5, 3.3	3.6 3.6	V
VI	Input Voltage		0		5.5	V
V _O	Output Voltage	(HIGH or LOW State) (3–State)	0 0		V _{CC} 5.5	V
I _{OH}	HIGH Level Output Current	$V_{CC} = 3.0 V - 3.6 V$ $V_{CC} = 2.7 V - 3.0 V$ $V_{CC} = 2.3 V - 2.7 V$			- 24 - 12 - 8	mA
I _{OL}	LOW Level Output Current	$V_{CC} = 3.0 V - 3.6 V$ $V_{CC} = 2.7 V - 3.0 V$ $V_{CC} = 2.3 V - 2.7 V$			+ 24 + 12 + 8	mA
T _A	Operating Free–Air Temperature		-40		+85	°C
$\Delta t / \Delta V$	Input Transition Rise or Fall Rate, V _{IN} from 0.8	V to 2.0 V, $V_{CC} = 3.0$ V	0		10	ns/V

ORDERING INFORMATION

Device	Package	Shipping [†]
MC74LCX245DW	SOIC-20	38 Units / Rail
MC74LCX245DWG	SOIC-20 (Pb-Free)	38 Units / Rail
MC74LCX245DWR2	SOIC-20	1000 Tape & Reel
MC74LCX245DR2G	SOIC-20 (Pb-Free)	1000 Tape & Reel
MC74LCX245DT	TSSOP-20*	75 Units / Rail
MC74LCX245DTR2	TSSOP-20*	2000 Tape & Reel
MC74LCX245M	SOEIAJ-20	40 Units / Rail
MC74LCX245MEL	SOEIAJ-20	2000 Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
*This package is inherently Pb–Free.

DC ELECTRICAL CHARACTERISTICS

			T _A = −40°C	to +85°C	
Symbol	Characteristic	Condition	Min	Max	Unit
V _{IH}	HIGH Level Input Voltage (Note 2)	$2.3 \text{ V} \leq \text{V}_{\text{CC}} \leq 2.7 \text{ V}$	1.7		V
		$2.7 \text{ V} \leq \text{V}_{\text{CC}} \leq 3.6 \text{ V}$	2.0		
V _{IL}	LOW Level Input Voltage (Note 2)	$2.3~\textrm{V} \leq \textrm{V}_{\textrm{CC}} \leq 2.7~\textrm{V}$		0.7	V
		$2.7 \text{ V} \leq \text{V}_{\text{CC}} \leq 3.6 \text{ V}$		0.8	
V _{OH}	HIGH Level Output Voltage	2.3 V \leq V_{CC} \leq 3.6 V; I_{OL} = 100 μA	V _{CC} – 0.2		V
		$V_{CC} = 2.3 \text{ V}; \text{ I}_{OH} = -8 \text{ mA}$	1.8		
		$V_{CC} = 2.7 \text{ V}; I_{OH} = -12 \text{ mA}$	2.2		
		V _{CC} = 3.0 V; I _{OH} = -18 mA	2.4		
		V _{CC} = 3.0 V; I _{OH} = -24 mA	2.2		
V _{OL}	LOW Level Output Voltage	$2.3 \text{ V} \leq \text{V}_{CC} \leq 3.6 \text{ V}; \text{ I}_{OL} = 100 \mu\text{A}$		0.2	V
		V _{CC} = 2.3 V; I _{OL} = 8 mA		0.6	
		V _{CC} = 2.7 V; I _{OL} = 12 mA		0.4	
		V _{CC} = 3.0 V; I _{OL} = 16 mA		0.4	
		V _{CC} = 3.0 V; I _{OL} = 24 mA		0.55	
l _l	Input Leakage Current	$2.3 \text{ V} \le \text{V}_{CC} \le 3.6 \text{ V}; 0 \text{ V} \le \text{V}_{I} \le 5.5 \text{ V}$		±5	μΑ
I _{OZ}	3-State Output Current	$\begin{array}{l} \textbf{2.3} \leq \textbf{V}_{CC} \leq \textbf{3.6 V}; \ \textbf{0V} \leq \textbf{V}_{O} \leq \textbf{5.5 V}; \\ \textbf{V}_{I} = \textbf{V}_{IH} \text{ or } \textbf{V}_{IL} \end{array}$		±5	μΑ
I _{OFF}	Power-Off Leakage Current	$V_{CC} = 0 V; V_{I} \text{ or } V_{O} = 5.5 V$		10	μA
I _{CC}	Quiescent Supply Current	$2.3 \le V_{CC} \le 3.6 \text{ V}; \text{ V}_{I} = \text{GND or } \text{V}_{CC}$		10	μA
		$2.3 \le V_{CC} \le 3.6 \text{ V}; 3.6 \le V_{I} \text{ or } V_{O} \le 5.5 \text{ V}$		±10	
ΔI_{CC}	Increase in I _{CC} per Input	$2.3 \le V_{CC} \le 3.6 \text{ V}; \text{ V}_{IH} = V_{CC} - 0.6 \text{ V}$		500	μA

2. These values of V_I are used to test DC electrical characteristics only.

AC CHARACTERISTICS $t_R = t_F = 2.5 \text{ ns}; R_L = 500 \Omega$

					Lin	nits			
					T _A = -40°	C to +85°C			
			V _{CC} = 3.3	$3 \text{ V} \pm 0.3 \text{ V}$	V _{CC} =	= 2.7 V	V _{CC} = 2.5	$V \pm 0.2 V$	
			C _L =	50 pF	C _L =	50 pF	C _L =	30 pF	
Symbol	Parameter	Waveform	Min	Max	Min	Max	Min	Max	Unit
t _{PLH} t _{PHL}	Propagation Delay Input to Output	1	1.5 1.5	7.0 7.0	1.5 1.5	8.0 8.0	1.5 1.5	8.4 8.4	ns
t _{PZH} t _{PZL}	Output Enable Time to High and Low Level	2	1.5 1.5	8.5 8.5	1.5 1.5	9.5 9.5	1.5 1.5	10.5 10.5	ns
t _{PHZ} t _{PLZ}	Output Disable Time From High and Low Level	2	1.5 1.5	7.5 7.5	1.5 1.5	8.5 8.5	1.5 1.5	9.0 9.0	ns
t _{OSHL} t _{OSLH}	Output-to-Output Skew (Note 3)			1.0 1.0					ns

 Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}); parameter guaranteed by design.

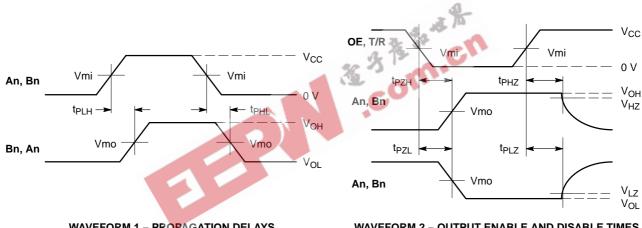
DYNAMIC SWITCHING CHARACTERISTICS

			T _A = +25°C			
Symbol	Characteristic	Condition	Min	Тур	Max	Unit
V _{OLP}	Dynamic LOW Peak Voltage (Note 4)	$ \begin{array}{l} {\sf V}_{CC}=3.3 \; {\sf V}, \; {\sf C}_{L}=50 \; {\sf pF}, \; {\sf V}_{IH}=3.3 \; {\sf V}, \; {\sf V}_{IL}=0 \; {\sf V} \\ {\sf V}_{CC}=2.5 \; {\sf V}, \; {\sf C}_{L}=30 \; {\sf pF}, \; {\sf V}_{IH}=2.5 \; {\sf V}, \; {\sf V}_{IL}=0 \; {\sf V} \end{array} $		0.8 0.6		V V
V _{OLV}	Dynamic LOW Valley Voltage (Note 4)	$ \begin{array}{l} {\sf V}_{CC} = 3.3 \; {\sf V}, \; {\sf C}_{L} = 50 \; {\sf pF}, \; {\sf V}_{IH} = 3.3 \; {\sf V}, \; {\sf V}_{IL} = 0 \; {\sf V} \\ {\sf V}_{CC} = 2.5 \; {\sf V}, \; {\sf C}_{L} = 30 \; {\sf pF}, \; {\sf V}_{IH} = 2.5 \; {\sf V}, \; {\sf V}_{IL} = 0 \; {\sf V} \end{array} $		-0.8 -0.6		V V

4. Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Unit
C _{IN}	Input Capacitance	V_{CC} = 3.3 V, V_{I} = 0 V or V_{CC}	7	pF
C _{I/O}	Input/Output Capacitance	V_{CC} = 3.3 V, V_{I} = 0 V or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	10 MHz, V_{CC} = 3.3 V, V_I = 0 V or V_{CC}	25	pF

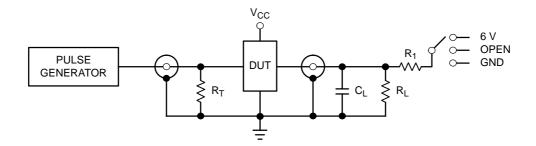


WAVEFORM 1 – PROPAGATION DELAYS $t_R = t_F = 2.5 \text{ ns}, 10\% \text{ to } 90\%; f = 1 \text{ MHz}; t_W = 500 \text{ ns}$

WAVEFORM 2 – OUTPUT ENABLE AND DISABLE TIMES $t_R = t_F = 2.5$ ns, 10% to 90%; f = 1 MHz; $t_W = 500$ ns

	V _{CC}				
Symbol	3.3 V \pm 0.3 V	2.7 V	2.5 V \pm 0.2 V		
Vmi	1.5 V	1.5 V	V _{CC} /2		
Vmo	1.5 V	1.5 V	V _{CC} /2		
V _{HZ}	V _{OL} + 0.3 V	V _{OL} + 0.3 V	V _{OL} + 0.15 V		
V _{LZ}	V _{OH} – 0.3 V	V _{OH} – 0.3 V	V _{OH} – 015 V		

Figure 3. AC Waveforms

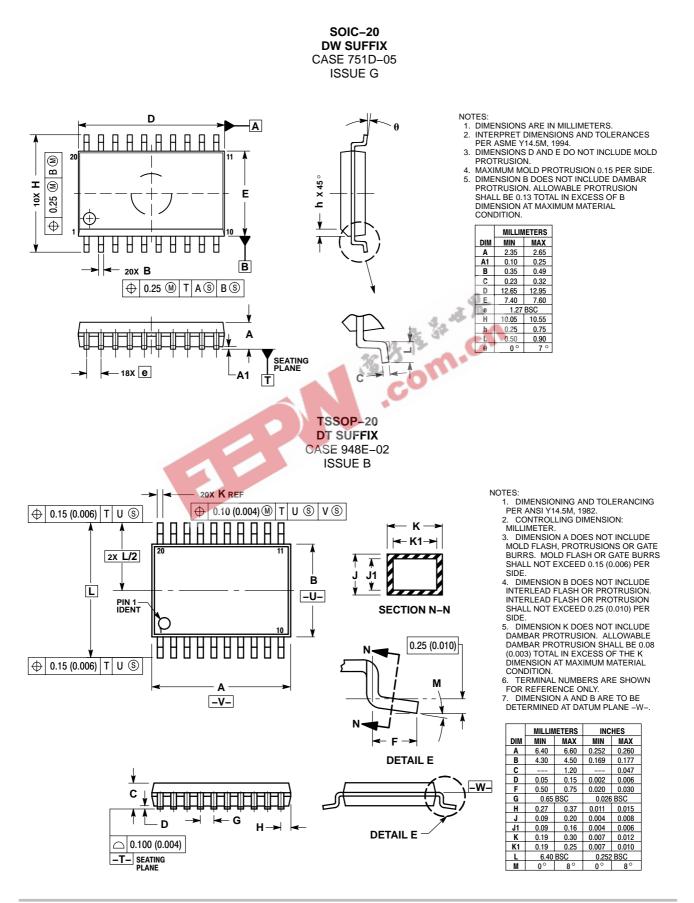


TEST	SWITCH
t _{PLH} , t _{PHL}	Open
t _{PZL} , t _{PLZ}	6 V at V_{CC} = 3.3 ± 0.3 V 6 V at V_{CC} = 2.5 ± 0.2 V
Open Collector/Drain t_{PLH} and t_{PHL}	6 V
t _{PZH} , t _{PHZ}	GND

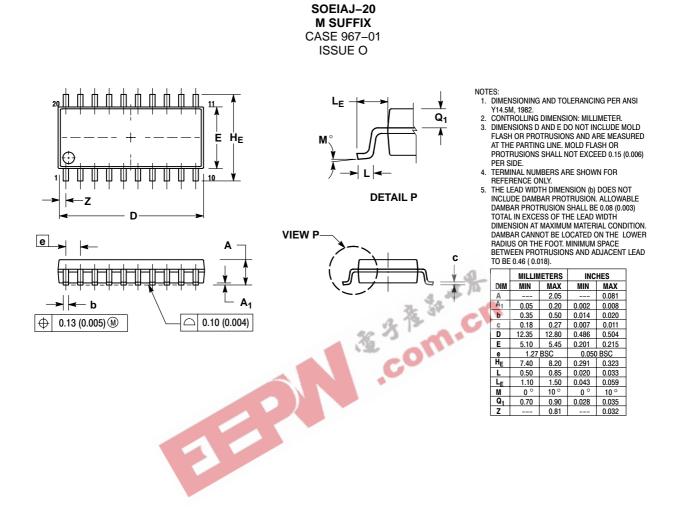
tpzH, tpHzGND $C_L = 50 \text{ pF at } V_{CC} = 3.3 \pm 0.3 \text{ V}$ or equivalent (includes jig and probe capacitance) $C_L = 30 \text{ pF at } V_{CC} = 2.5 \pm 0.2 \text{ V}$ or equivalent (includes jig and probe capacitance) $R_L = R_1 = 500 \Omega$ or equivalent $R_T = Z_{OUT}$ of pulse generator (typically 50 Ω)Figure 4. Test Circuit



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